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To cite this version:

D Saa, T. Gries, S Migot-Choux, J. Ghanbaja, P. Boulet, et al.. Synthesis of RuO$_2$ Nanowires by Alkali-Assisted Oxidation of Ruthenium in Plasma Afterglow at Atmospheric Pressure. IEEE Transactions on Nanotechnology, Institute of Electrical and Electronics Engineers, 2017, 10.1109/TNANO.2017.2699861. hal-02106036

HAL Id: hal-02106036
https://hal.univ-lorraine.fr/hal-02106036
Submitted on 22 Apr 2019

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Synthesis of RuO$_2$ Nanowires by Alkali-Assisted Oxidation of Ruthenium in Plasma Afterglow at Atmospheric Pressure

D. Kuete Saa, T. Gries, S. Migot-Choux, J. Ghanbaja, P. Boulet, S. Laminis, T. Belmonte

Abstract—RuO$_2$ nanowires are synthesized by oxidation of ruthenium thanks to a micro-post-discharge at atmospheric pressure. However, RuO$_2$ nanowires form islands. The growth mechanism depending on surface defects, the surface density of the nanowires is limited. We report on the influence of two alkali salts, NaCl and KCl, deposited as grains on ruthenium to act as defects and increase the nanowire density. These grains induce the growth of RuO$_2$ nanowires all around them, creating a circular area where nanowires are found. Nanowires start growing at the triple point at the grain base where the alkali-salt grain, ruthenium from the substrate and oxidizing gaseous species coexist. When nanowires grow, the stress induced in the surrounding layer creates new cracks, making possible the radial propagation of the nanowires. The presence of nanowires on grains is due to the etching mechanism that converts the alkali salt into an oxide, enabling onward oxidation of ruthenium.

Index terms—Ruthenium oxide, nanowires, plasma oxidation, afterglow, atmospheric pressure

INTRODUCTION

LOW PRESSURE plasmas are known to be fast processes to synthesize one-dimensional nanostructures [1–6]. The importance of ion bombardment on the anisotropic growth of these objects is crucial. At atmospheric pressure, ion bombardment being negligible, other strategies have to be developed in order to get high growth rates.

The group of M. K. Sunkara proposed several methods [1, 7] to achieve this goal. One way of synthesizing metal oxide nanowires at ultrahigh rates (on the scale of a minute) [8–11] relies on the combination of a transition metal or a transition metal oxide with an alkali salt, like NaCl or KCl, to produce a mixture which is treated by a plasma at atmospheric pressure. This process mimics somehow the hydrothermal synthesis technique.

A high contact surface between the metal and alkali particles is mandatory. This can be achieved either by sprinkling alkali particles on a metal foil or by mixing intimately alkali and metal powders. Like this, an alkali metal metallate is synthesized. Next, this compound must be purified by dipping in an HCl solution (substitution of the alkali in the metallate by hydrogen) and either annealed or exposed to oxygen plasma (removal of hydrogen).

Basically, the role of the plasma in this alkali-assisted process is simply practical, the plasma acting as a heat source. Indeed, O$_2$ in its neutral state is proposed to be the main oxidizing species. This conclusion is consistent with the high synthesis temperature, which is close to 1273 K in this process.

In this work, the strategy proposed by the group of M. K. Sunkara is applied to a ruthenium substrate covered by NaCl or KCl grains. Indeed, ruthenium dioxide RuO$_2$ is a key material for supercapacitors [12–14] in which it has to be present with the highest possible specific surface area to store electrons.

Music et al. [15] demonstrated from the suggestion by Lin et al. [16] that the presence of the gaseous hyperoxide RuO$_2$ is relevant for the formation of nanorods. Lin et al. [16] showed that RuO$_2$ was deposited by reactive sputtering of ruthenium in an oxidizing atmosphere as a relatively smooth film at 473 K, then as a pile of short rods at 573 K, and finally as perfectly faceted nanorods at 723 K. According to Hsu et al. [17], although ruthenium etching in ICP plasmas correlates well with the oxygen radical density, chlorine-containing species also play a role.

In a previous work [18], we showed that the synthesis of RuO$_2$ nanowires was possible by oxidation with an atmospheric microwave micro-afterglow on a ruthenium substrate. The use of a non-equilibrium medium allows a lowering of the temperature in respect of thermal oxidation, given that molecular oxygen is excited or dissociated, which provides more reactive species such as singlet oxygen O$_2$(a`$\Delta_g$) or atomic oxygen. This improves the anisotropy of growth, and then, the synthesis of nanowires.

In these specific conditions, ruthenium oxidation produces a general nanostucture made of lamellae spaced 20-50 nm apart within a temperature range of [530 K - 820 K]. Spread over the surface, localized bundles of nanowires are formed with an occurrence that depends on the temperature. The growth mechanism of the localized bundles is driven by stress from emerging defects, as explained in one of our former works on
silicon oxidation by the same process [19, 20]. Oxidation of ruthenium was proposed to proceed this way:

\[
\text{Ru}^{ii} + 4e^- + (2O \text{ or } O_2) \rightarrow \text{RuO}_2
\]  

(1)

Metals with “valve” native oxides, i.e. dense oxides that stop diffusional processes like SiO2, ZrO2 or RuO2, get oxidized by forming these bundles where surface defects act as weak points enabling diffusion.

In this work, we choose to introduce voluntarily "defects" in a controlled manner by depositing on the surface of ruthenium, micro-grains of alkali salts to serve as preferential sites for the growth of nanowires. The idea is to enhance the surface density of RuO2 nanowires, salts being next easily removed by dissolution in water. A special attention will be paid to the growth mechanism of the nanowires.

II. EXPERIMENTAL SET-UP

The experimental set-up is shown in Fig. 1. An atmospheric Ar-O2 microwave plasma is ignited in a fused silica tube (27 mm inner diameter) placed in a 2.45 GHz resonant cavity. The power absorbed by the plasma is 100 W. Flow rates of gases are controlled by two mass flow controllers and the total flow rate is 825 sccm (standard cubic centimeter per minute). The partial pressure of oxygen in the gas mixture is set at 7.5 vol.%. The treatment time is 2 hours. The micro-afterglow is visible as a light beam escaping a hole (600 µm in diameter) drilled in a brass plate screwed on one wall of the cavity [14]. Light emission is due to NO radiative species produced by reaction between oxidizing active species in the afterglow and nitrogen from the ambient air. These species are mainly O, O2(a) and O2(X) because the afterglow is too hot to produce O3 typically, the rotational temperature of OH molecules – due to the water flux from the surrounding air – determined by optical emission spectroscopy in the present conditions is ~1000 K at the nozzle exit [14]. However, far enough from the beam (and then from the treated spot on the substrate surface), O3 can be detected.

Samples are cuboids (5×5×3 mm³) of high purity metallic ruthenium (99.99%). They are polished mechanically (final stage 1 µm diamond paste), ultrasonically cleaned in acetone and rinsed with ethanol before treatment. The sample-nozzle distance is set at 4.5 mm.

NaCl and KCl are used as alkali sources. They are dissolved in water at different concentrations (0.04, 0.08 and 0.16 g mL⁻¹). Next, the ruthenium substrate is spin-coated by a solution of that type and water is evaporated in the air at room temperature. This gives large grains of alkali salts on the surface, ranging typically from 5 µm to 20 µm in diameter. The wettability of the solution on ruthenium is about 70°. Another procedure was applied to enhance the surface coverage by smaller grains. The ruthenium samples are pretreated in a low pressure nitrogen afterglow to decrease the wettability (conditions: pressure: 1 mbar, microwave power: 100 W, gas mixture: Ar (500 sccm)−N2 (100 sccm), distance from gap: 1 m, processing temperature: 320 K, treatment duration: 10 min). The sample is spin-coated by the solution and put under primary vacuum (1 mbar) to evaporate the water much faster to limit coarsening and get smaller size distribution of alkali salt grains. In this case, grains are found aligned along surface scratches with mean diameters inferior to 5 µm and the wettability of solution is around 30°.

An important aspect of micro-afterglow treatment deals with the radial temperature distribution on the sample surface. Although ruthenium tetroxide RuO2 sublimes at 313 K, it can be synthesized as solid above this temperature. Starting from pure ruthenium, and only in this condition, oxidation below 473 K produces solid RuO2 and solid RuO3 [16]. This latter oxide can be further oxidized into solid RuO2 between 523 and 573 K [16]. In the present work, ruthenium is always covered by a RuO2 passive layer. Consequently, ruthenium tetroxide being gaseous above 900 K [17, 19], the hottest part of the surface hit by the afterglow beam is continuously evaporated and cannot support any nanowire growth. Gaseous RuO3 is emitted at slightly higher temperature (~1000 K after [17]). If the sample is large and thick enough to create thermal gradients, this phenomenon leads to the formation of a void with a diameter where the temperature is higher than 900 K (see Fig. 1a).

In the present conditions, we demonstrated that the size of the samples do not allow any significant temperature gradient (below 4 K) in the whole volume of these small (5×5×3 mm³) metallic cuboids [18]. Because no void was ever observed in the present treatments, the surface temperature was always below 900 K. It was estimated to be 570 ± 20 K [18].

Treated surfaces were characterized by Scanning Electron Microscopy (SEM), X-Ray Diffraction (XRD) and Transmission Electron Microscopy (TEM). X-ray measurement were performed with a Bruker D8 Diffractometer using a point focus beam and the CoKα wavelength (λ = 0.179026 nm)

III. RESULTS AND DISCUSSION

Without alkali salts, afterglow oxidation of ruthenium produces a general nanostructure made of lamellae spaced 20-50 nm apart within a temperature range of [530 K - 820 K] [18]. Spread over the surface, sea-urchin-like localized objects made of concentric rings of nanowires are formed with an occurrence that depends on the temperature. Their growth is driven by stress from emerging defects [18, 20]. An emerging dislocation, for instance, acts as a preferential path to transport ruthenium from the substrate core to the surface. Injection of interstitial metallic ions certainly occurs at the inner interface.
The nanowire grows by outward diffusion of ruthenium. Oxygen atoms feed directly the nanowire. These atomic species, readily available in afterglow – because no dissociation of molecular oxygen is needed – are required at very low temperature. The outward diffusion of silicon is balanced by the inward diffusion of vacancies. Their agglomeration creates Kirkendall porosity at the inner interface and this phenomenon can eventually limit the growth. When the nanowire grows, it induces a radial stress field in the passive oxide layer until new defects appear at the surface, close to it. A new nanowire starts growing and the process perpetuates gradually, forming sea-urchin-like structures.

A. Nanowires morphology

When NaCl grains are sprinkled on ruthenium, they create preferential local active sites to initiate the nanowires growth. Crystalline grains exhibit well-faceted shapes with sharp edges (see supplemental material 1). In Fig. 2, we observe the formation of nanowires on NaCl grains from the afterglow center outwards (up to 2.5 mm) after a two-hour treatment. These grains are, most often, the centers of circular areas in which nanowires are found. By comparison with results from our former work [18], the surface density of these areas increases by a factor of 17 (from $1 \times 10^4 \text{ cm}^{-2}$ to $17 \times 10^4 \text{ cm}^{-2}$ for a 2-hour treatment), areas having similar diameters in both cases. They lie between 2 $\mu$m and 23 $\mu$m without NaCl and between 3 $\mu$m and 35 $\mu$m with NaCl.

In Fig. 4, we can observe how bundles of nanowires grow around NaCl grains.

The radial evolution of nanowires exhibits similar features with KCl instead of NaCl (Fig. 3). The most striking difference lies in the shape of the nanowires which is much thicker (their diameter varies from ~500 nm to ~2 $\mu$m while the diameter of nanowires obtained in the presence of NaCl is ~200 nm). Another interesting feature of KCl grains is their complete capping by nanowires, whatever their size. NaCl grains are most often only decorated on edges, even though the smallest grains can be completely capped by nanowires.

These crystalline grains exhibit sharp edges before the appearance of nanowires (Fig. 4a). When nanowires start growing, they form bundles attached to grain edges. Patently,
edges are etched and adopt locally the curvature radii of the bundles (Fig. 4b). When the grain height is high, nanowires appear only at the base of the grain (Fig. 4a). If the grain is small enough, both in height and in size, it can be completely converted (Fig. 4b). Consequently, the longest nanowires are found at the triple point where NaCl, Ru from the substrate and oxidizing gaseous species are simultaneously found, i.e. the boundary of square that defines the NaCl or KCl grain base. The fact that only the small grains of NaCl are covered by nanowires results from the overlapping of nanowire bundles growing from opposite sides. This is readily observed in Fig. 4b (grain at the top of the image, for example). In Fig. 5, we observe that nanowires can also grow between grains. We explained previously that it was possible to grow these nanowires without alkali salts [18]. Then, when grains are sprinkled on ruthenium, the growth of nanowires between these grains is generally observed far from the center, at the edge of the sample, on the coldest areas. The growth from emerging surface defects is always possible in our conditions but the growth from grain edges requires a minimum temperature.

\[ \text{Fig. 5. a) Example of nanowires grown around NaCl grains. b) Idem around KCl grains.} \]

C. X-ray Analysis

X-ray measurements were performed at grazing incidence for two reasons: on one hand, the layer of oxide is thin, and the grains of NaCl are relatively small (of the order of one micrometer) and of moderate density on the other hand. Measurements at grazing incidence (4° in our case) are thus required to increase the ratio of the probed volumes of RuO\(_2\) to Ru. Fig. 6 shows respectively XRD patterns of a pure ruthenium substrate (Ru), a ruthenium substrate covered by NaCl grains (Ru+NaCl) and a ruthenium substrate covered by NaCl and oxidized by micro-afterglow (Ru+NaCl+RuO\(_2\)). The analysis performed on Ru+NaCl shows, besides the peaks of the substrate, those of sodium chloride. NaCl peaks are identified respectively at 2θ = 37.3° (200), at 2θ = 53.1° (220), at 2θ = 66.6° (222) at 2θ = 90.6° (420) and 2θ = 102.1° (422). When the spectrum obtained after oxidation by micro-afterglow (Ru+NaCl+RuO\(_2\)) is superimposed on the spectra of Ru and Ru+NaCl, there appear new peaks which are assigned to ruthenium dioxide (RuO\(_2\)). Among these peaks, we can note the following peaks: (110), (101) and (211) respectively at 2θ = 33.3°, 2θ = 41.5° and 2θ = 64.4°. No other phase is observed.

Identical conclusions are drawn if the alkali salt is potassium chloride (see supplemental material 2).

\[ \text{Fig. 6. X-ray patterns (Laue00) of ruthenium sample (black), of ruthenium substrate covered by NaCl grains (red) and of ruthenium substrate covered by NaCl and which was oxidized by micro-afterglow plasma (blue).} \]

D. Nanowires Crystalline Structure

TEM analyses of nanowires grown with NaCl show that two types of nanowires are synthesized: feather-like nanostructures and single or bi-crystal nanowires (Fig. 7). Micro-diffraction analyses indicate that both types of nanowires can be indexed by RuO\(_2\) (rutile P\(_4\)/mnm, \(a = 4.4919\) Å; \(c = 3.1066\) Å).

Fast Fourier Transform (FFT) analysis applied to high-resolution TEM (HRTEM) image (Fig. 8) confirms that the as-synthesized nanowires are tetragonal RuO\(_2\) phase [22] with a single crystalline structure. The spacing between two adjacent planes is about 3.18 Å (Fig. 8b), which is consistent with the lattice parameter expected for the (110) plane of the tetragonal phase of RuO\(_2\) (the theoretical value is 3.176 Å). The growth direction of the resulting nanowires is [1–10] in the given example, but we found no preferential orientation after analysis of a large number of nanowires.
The elemental composition analysis of as-synthesized RuO$_2$ nanowires (see supplemental materials 3 and 4) was determined by STEM-EDS (Scanning Transmission Electron Microscopy–Energy Dispersive Spectroscopy). Micro-EDS analysis is rarely very accurate because of the need to have a straight pathway of emerging X-rays to the detector. On a large set of nanowires, this technique shows that sodium is detected at low concentrations (about 2–5 at %), which is also true for KCl, its concentration varying from 1 to 3%. Chlorine is not found because its corresponding signal is overlapped by ruthenium.

From these profiles, it is clear that some parts of the nanowire do not contain any alkali element. Therefore, we infer that the alkali elements are distributed on the surface of the nanowire and not in its volume. Very likely, particles of NaCl or KCl get attached to the nanowire during its growth, leading to the weak concentration reported in our measures (see supplemental material 5). These analyses do not prove once and for all that alkali elements are not present in the core of the nanowire, but they clearly show that, if they are, their concentration is very limited. Since the presence of an alkali salt on nanowires has no measurable influence on the crystal lattice of ruthenium dioxide, this allows us to exclude the possible formation of eutectics. For sodium ruthenate phases, one finds: NaRuO$_2$ [23], Na$_2$RuO$_4$ [24, 25], NaRuO$_6$ [26], Na$_2$Ru$_4$O$_9$ [26, 27], Na$_3$RuO$_4$ [26, 27], Na$_3$RuO$_6$ [26], Na$_3$Ru$_4$O$_9$ [26], Na$_3$Ru$_4$O$_{10}$ [26, 28], Na$_3$RuO$_4$ [27], Na$_5$Ru$_4$O$_8$ [27] and Na$_7$Ru$_4$O$_{18}$ [29]. Beside, oxyhydrates can also form after air exposition, like Na$_3$RuO$_2$.$\gamma$H$_2$O (x = 0.22, y = 0.45) [23].

In the case of KCl, several potassium ruthenate phases are currently listed: KRuO$_3$ [30], KRu$_2$O$_5$ [31], K$_3$Ru$_2$O$_6$ [32], K$_3$RuO$_4$ [33], K$_2$Ru$_4$O$_7$ [34] and K$_2$RuO$_4$ [33]. Like sodium ruthenates, oxyhydrates can be formed in humid air, like K$_3$Ru$_2$O$_2$.nH$_2$O (n = ~0, 0.5, 0.9) [35]. In every case, the concentrations of sodium and potassium in these phases are much higher than those measured experimentally.

**E. Nanowires growth mechanisms**

In order to try to monitor the nanowires growth obtained by oxidation of ruthenium substrate sprinkled with alkali salts, it is necessary to understand their possible growth mechanisms. In a previous work [18], we showed, in the same experimental conditions, that RuO$_2$ nanowires could be grown without alkali salts, with similar growth rates. Then, sprinkling salt crystals on the ruthenium surface creates additional “nucleation sites”. This technique is useful to localize the nanowire growth on the substrate at the specific spot where a grain is deposited. What is meant here by “nucleation site” is a local failure in the native RuO$_2$ layer to make access to the underlying reservoir of ruthenium. We assume that this failure occurs thanks to the creation of triple point at the base of the
grains. In order to verify this assumption, series of experiments were performed. First, we substituted the alkali salts by gold islands which do not react with micro-afterglow plasma (no possible oxidation). The experimental procedure was as follow: a gold layer (about 50 nm) is formed through the interstices of a TEM grid placed on the ruthenium substrate (Fig. 10a). When the grid is removed, two areas are observed: one masked by gold and one free of gold (Fig. 10b). The patterned surface is next oxidized by the micro-afterglow. In the area masked by gold, no nanostructure is found (Fig. 10c). In contrast, the gold-free area is characterized by a nanostructure made of lamellae with localized bundles of nanowires (Fig. 10d), as commonly observed on a ruthenium sample without any alkali salt. Therefore, gold is inert and does not catalyze the formation of nanowires. Due to this chemical inertness, gold does not allow to have nanowires at the edge of gold plots (no triple point) as with NaCl or KCl. Second, experiments were made by substituting NaCl and KCl by their homologous NaI and KI at the same concentrations. The experimental conditions were unchanged. It turns out that the growth of nanowires proceeds as with chlorine (see supplemental material 6). Nanowires are a bit shorter, maybe because of the lower reactivity of iodine with regard to chlorine, but the growth mechanism is basically unchanged. Third, the role of water was checked. As the micro-afterglow is operated in air, because of the high reactivity of salts with water, we chose to introduce water on purpose to evaluate its role on the growth of nanostructures. In Fig. 11, SEM images of nanowires grown around NaCl grains for water flow rates in the range [0-1.33] sccm are depicted. The etching of the grains is all the more efficient as the flow rate of water increases. It is important to note that etching by water affects the whole grain, including the central part, whereas without water, only the edges are etched. The growth of the nanowires occurs at the base of the grains and it is not affected, as far as we can estimate it, by the partial pressure of water. The key point here is that the partial pressure of water coming from the surrounding air in the Ar-O_2 afterglow is negligible because no general etching occurs without water introduced on purpose. Then, O or O_2^- are the active species that do control the growth of RuO_2 nanowires. Moreover, direct reaction between NaCl or KCl with O or O_2^- to produce Na_2O or K_2O, whose melting points are about 1405 K and 1010 K respectively, are unlikely. By looking at a sufficiently narrow spot where several similar grains are found, we can assume that the same conditions prevail, i.e. same concentration in active species and same temperature. In Fig. 12, we clearly notice that, although the conditions are the same, one NaCl grain behaves singularly.

We infer from this observation that the nanowire growth is only possible if the alkali grain forms micro-cracks through the RuO_2 passive layer that opens access to ruthenium from the underlying reservoir.

In Fig. 13a, the nanowire density is observed to be maximal at about 1 µm from the edge. The presence of corrosion pits between the wall of the grain and the nanowires is noteworthy (Fig. 13b). These corrosion pits are also found with iodides (see supplemental material 7). As explained hereafter, these pits are the results of the nanowire growth and not the origin.
Alkali salt grains can adopt specific shapes with thickness gradients. This happens when evaporation makes the water droplet, loaded in alkali salt, flow. In Fig. 14a, an example of such a NaCl grain with thickness gradient is given. After treatment, we notice that nanowires grow over the grain along specific directions indicated by arrows in Fig. 14b. If we zoom in (Figs. 14c and 14d), we observe that nanowires progress inward by forming juxtaposed bundles of nanowires that are smaller if they have just been formed. We also observe that this stepwise progression – which must not be confused with the formation of concentric rings outward – also occurs along grain edges (circle area in Fig. 14b). From these observations, it seems likely that the inward propagation process is limited by surface diffusion. Besides, a nucleation step seems required to form, on an activated site, a new bundle of nanowires.

We can now draw a general picture of the formation of nanowires. The growth of nanowires near alkali salt grains is associated with the existence of a triple point where the alkali chloride or iodide, the ruthenium dioxide and active oxygen are present simultaneously. Contrary to nanowire bundles growing from emerging defects on surface that are not covered by alkali salt, the formation of nanowire along the edges of grains is linked to a localized corrosion process based on the synthesis of a gaseous mediator. Indeed, this mechanism no longer operates with gold but does with iodides.

To explain the corrosion mechanism, we have to assume that reaction (1) is replaced by another one where NaCl (or KCl) is present.

\[ \text{Ru}^{4+} + 4\text{NaCl} \rightarrow \text{RuCl}_4 + 4\text{Na}^+ \]  

(2)

No thermodynamic data is available about this process to the best of our knowledge. Even the enthalpy of formation of RuCl₄ is unknown. If this process does occur, the possibility of a chemical vapor deposition process comes up.

\[ \text{RuCl}_4 + (2\text{O} \pm \text{O}_2^*) \rightarrow \text{RuO}_2 + 2\text{Cl}_2 \]  

(3)

However, such a process seems unlikely for it leads to nanowires only by Vapor-Liquid-Solid or by self-catalysis like with ZnO [36], Si and Ga [37], GaN [38], SiC [39], etc. In the former process, a catalyst is needed, which is not observed here, whereas in the latter, it would not explain the stepwise behavior of the propagation process.

Reactions (1) and (2) cannot occur simultaneously but they can occur successively. Indeed, the growth process of a nanowire assumes the transportation of a metallic ion over several tens of micrometers before reaction (1) occurs. The propagation process is then limited by chemical reaction and not by diffusion, which is due to the low synthesis temperature. Then, Ru⁺⁺ ions attack sodium chloride first and transform NaCl into Na⁺. The synthesis of the oxide from Na⁺ would read:

\[ 2\text{Na}^+ + 2\text{e}^- + \text{O} \rightarrow \text{Na}_2\text{O} \]  

(4)

Islands of sodium oxide can form and, without chlorine, reaction (1) will be once again possible.

Thus, the formation of nanowires at the edge of grains is likely due to the presence of micro-cracks induced by that mechanical stress that breaks the continuity between the grains and the thin film of salt in the vicinity of the grain. The breakage could be easily induced by the difference of the expansion coefficients of Ru and NaCl or KCl. Indeed, these coefficients are, at 300 K, 6.4×10⁻⁶ K⁻¹ and 40×10⁻⁶ K⁻¹ for NaCl or 36×10⁻⁶ K⁻¹ for KCl, i.e. about a factor of 6 between both values.

The above set of reactions, which explains the possible growth mechanism for alkali metal-assisted growth of RuO₂ at triple point, is summarized by Fig. 15. Each grain is deposited as a crystal on the passivated ruthenium substrate (step a in Fig. 15). When the plasma is turned on, thanks to thermal gradients, cracks open at the edge of grains, enabling the outward diffusion of ruthenium ions (step b). Then, the nanowires start growing (step c). The succession of chemical reactions (reactions 2, 4 and 1) at the surface of the alkali salt permits a progressive inward propagation of the nanostructure over the grain (step d). This step is accompanied by a depletion of the alkali salt that is consumed as time passes. We assume at this stage that surface transport and reactivity of the released ions, which depend on the local conditions prevailing around each grains, might play a role on the growth kinetics of the wires. However, no such information is available yet and this will be investigated in forthcoming works. The outward propagation that forms concentric circles around the grain is due to the formation of the defects by stress (step e), as explained in a former work of ours [18, 20]. Vacancies accumulate in ruthenium, forming Kirkendall porosity and leading to a self-limitation of the process.
This growth mechanism is very different from the mechanism proposed by Kumar et al. [21] because of the low temperatures of the micro-afterglow compared with direct plasma (T~1300 K [8] vs T < 600 K [18]). The role played by alkali salts is then more “mechanical” than “chemical” in our conditions.

IV. CONCLUSION

We proposed an original process to grow ruthenium oxide nanowires (by alkali-assisted oxidation). The presence of salt grains enhances the growth of the nanowires all around them, creating a circular area where nanowires are found. Their average length decreases radially, from the grain outward. XRD, HRTEM and FFT analysis confirmed that the as-synthesized nanowires are tetragonal RuO2 phase. They grow typically at temperature ~ 570 K. The growth mechanism of nanowires occurs at the triple point created around the grains (where there coexist NaCl, Ru and oxidizing gaseous specie) and this was verified by substituting on one hand NaCl or KCl by gold which does not react with microwave afterglow plasma and on other hand by Na or KI grains which are generally less reactive than NaCl or KCl. This technique could be useful to localize the growth of nanowires along specific lines forming complex patterns and drawn by edges of grains with shapes that would be made on-demand.

ACKNOWLEDGMENT

The “Service de Coopération et d’Action Culturelle” of the French embassy in Cameroon is gratefully acknowledged for the PhD grant of D. Kuetta Saa.

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Pascal Boulet did his PhD in Solid State Chemistry, in the frame of the European program “Human Capability and Mobility”. He performed his thesis work in the network composed of 4 different labs: Institut für Physikalische Chemie in Vienna (A), Dipartimento di Chimica e Chimica Industrial in Genova (I), the NCSR of Demokritos in Athens (GR) and the institut des Sciences Chimiques de Rennes (F). In 1999, after one year in Vienna as a post doc, he joined for 6 years, the Institut for Transuranium elements (EC-JRC) in Karlsruhe (G). In 2006, he spent 6 months at the synchrotron ANKA in Karlsruhe on the Institute for Nuclear Waste Disposal (INE) beamline, and got a permanent position in the CNRS at the Institut Jean Lamour in Nancy. He is in charge of a plateform called “centre de compétences XGamma” dealing for all X-ray and Mossbauer spectroscopy facilities for the institute. His research is shared between 3 different fields i) to look for new intermetallic phases showing interesting properties like magnetic ordering or superconductivity ii) to look for new quasicrystalline and approximant phases with rare earth, iii) and characterization of thin film by XRD. He is co-author of more than 100 papers in refereed international journals and in proceeding of international conferences.

Samuel Laminsi, Ph.D is the head of plasma chemistry of environment and materials team. He received his doctorate (3rd Cycle) in Inorganic Chemistry in 1989 from the University of Yaounde. He became Professor/Researcher at the University of Yaounde 1 since 1991. He also holds his Ph.D (2005) in Inorganic Chemistry from the University of Yaounde 1 and was promoted to full Professorship in 2015. Since 2009 he is the Director of Laboratory of Mineral Chemistry, Department of Inorganic Chemistry, Faculty of Science. Samuel Laminsi is the author/co-author of over 40 original research papers He also presented both orals and posters communications in international conferences Samuel’s research interests include Plasma synthesis of metal oxides (nanostructures and nanocomposites) and plasma treatment of waste water. He serves as a regular reviewer for numerous journals including Plasma Chemistry and Plasma Processing, Journal of Nanoscience and Nanotechnology, Environmental Monitoring and Assessment…

Thierry Belmonte is senior scientist at the Institut Jean Lamour, Nancy, France. He is an engineer who studied in Grenoble and obtained his PhD in material science in 1993. He became researcher of the CNRS the same year and was promoted Research Director in 2006. From 2009 to 2012, he managed the Institut Jean Lamour as deputy-director. He is member of the French’s National Vacuum Society and Physical Society. Thierry Belmonte’s research is mainly devoted to plasma nanoscience and, more recently, to plasmas in liquids. He published 202 papers, presented 323 posters or oral communications in conferences, 67 invited lectures, wrote 7 chapters in books and 6 patents. He was awarded the bronze medal of the CNRS and the first price of the Region Lorraine.